

In re Patent Application of

Jong Jin PARK et al.

Application No.: 10/814,264

Filing Date: April 1, 2004

Title: PHOTOSENSITIVE SEMICONDUCTOR

NANOCRYSTALS, PHOTOSENSITIVE

COMPOSITION COMPRISING

SEMICONDUCTOR NANOCRYSTALS

AND METHOD FOR FORMING SEMICONDUCTOR NANOCRYSTAL

PATTERN USING THE SAME

Group Art Unit: 2826

Examiner: THOMAS L DICKEY

Confirmation No.: 8445

SECOND INFORMATION DISCLOSURE STATEMENT TRANSMITTAL LETTER

Enclosed is a SECOND Information Disclosure Statement (IDS) and accompanying

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

NOV 0 9 2006

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

form P	TO-1449 for the above-identified patent application.
\boxtimes	No additional fee for submission of an IDS is required.
	The fee of \$ 180 as set forth in 37 C.F.R. § 1.17(p) is also enclosed.
\boxtimes	A statement under 37 C.F.R. § 1.97(e) is also enclosed.
	A statement under 37 C.F.R. § 1.97(e), and the fee of \$ 180 as set forth in 37 C.F.R. § 1.17(p) are also enclosed.
	Charge to Deposit Account No. 02-4800 for the fee due.
	A check in the amount of is enclosed for the fee due.
	Charge to credit card for the fee due. Form PTO-2038 is attached
\boxtimes	The Director is hereby authorized to charge any appropriate fees under 37 C.F.R. §§ 1.16, 1.17 and 1.21 that may be required by this paper, and to credit any overpayment, to Deposit Account No. 02-4800. This paper is submitted in duplicate.
	Respectfully submitted,

By:

BUCHANAN INGERSOLL & ROONEY PC

Date November 9, 2006

Benton S. Duffett, Jr.

Registration No. 22030

P.O. Box 1404 Alexandria, VA 22313-1404 703 836 6620

Buchanan Ingersoll & Rooney PC Attorneys & Government Relations Professionals

Attorney's Docket No. <u>1021269-000013</u>

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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SECOND INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. § 1.56, the accompanying information is being submitted in accordance with 37 C.F.R. §§ 1.97 and 1.98.

Pursuant to 37 C.F.R. § 1.98, a copy of each of the documents cited is enclosed. Also enclosed is a copy of an Official Notice of Reason for Rejection issued by the Korean Patent Office on August 28, 2006, which cites the references listed on the attached PTO-1449 Form. At this time, an English-language version of the Notice is not available to the undersigned attorney.

I, the undersigned, hereby state that each item of information contained in this Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three (3) months prior to the filing of this Information Disclosure Statement.

The documents are being submitted after a first Office Action on the merits but prior to the closing of prosecution, therefore under 37 C.F.R. § 1.97(c), a statement is enclosed.

To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that an Examiner initialed copy of this form be returned to the undersigned.

Respectfully submitted,

BUCHANAN INGERSOLL & ROONEY PC

Date: November 9, 2006

Benton S. Duffett, Jr. Registration No. 22,030

P.O. Box 1404 Alexandria, Virginia 22313-1404 (703) 836-6620

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